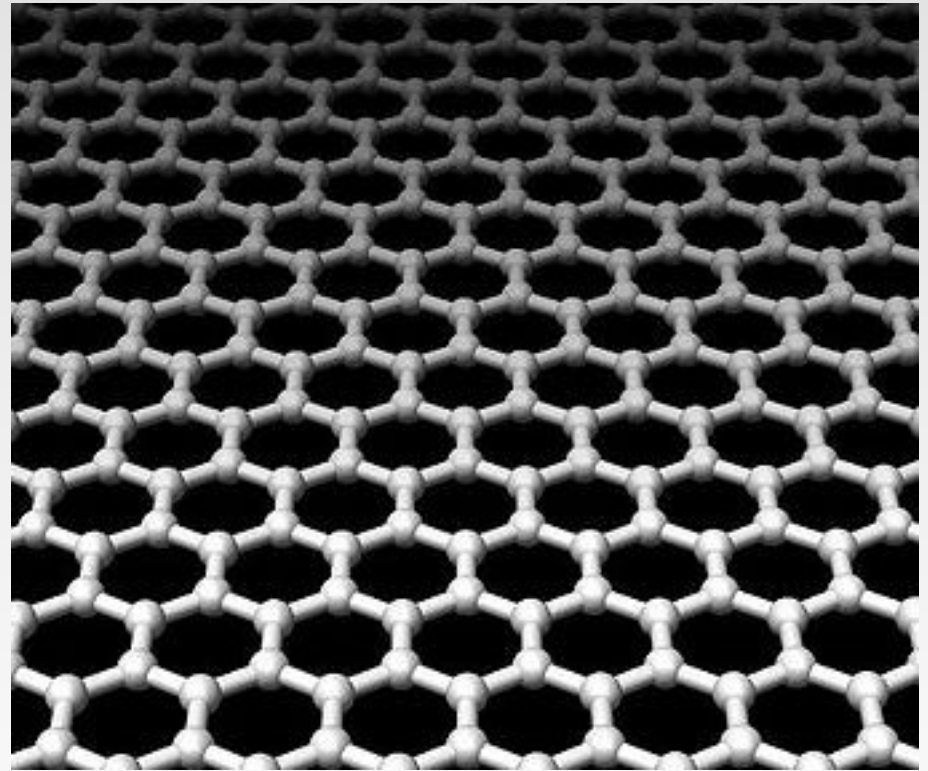


VASP exercises III

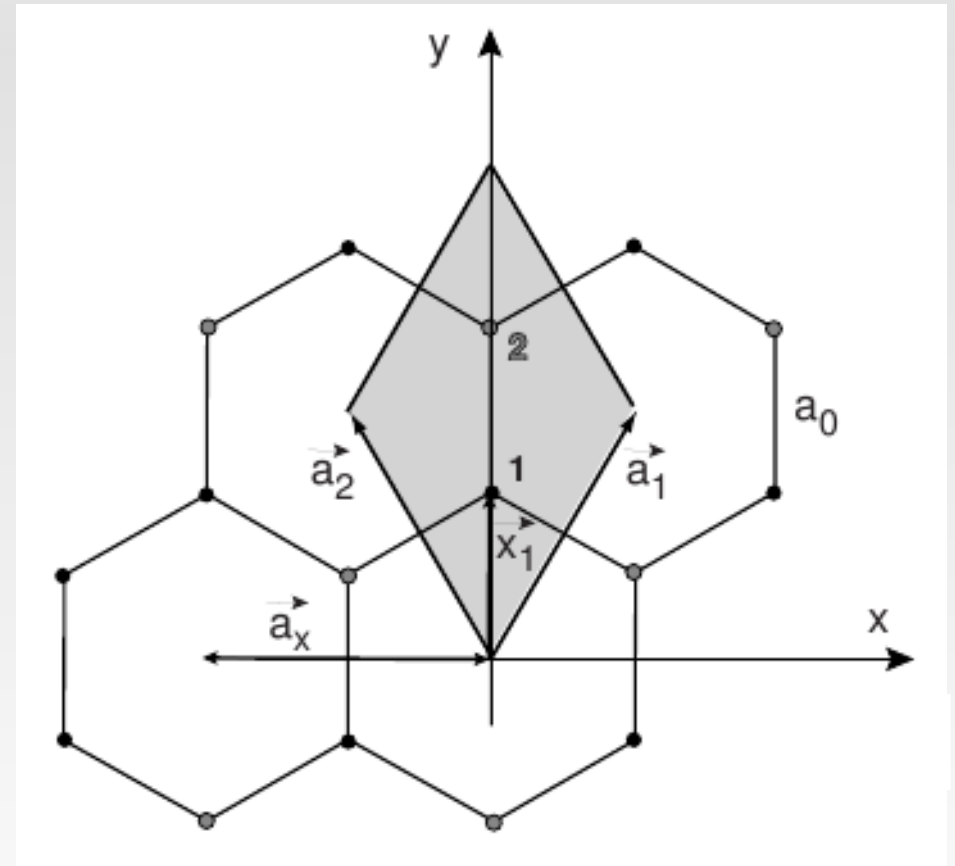
Outline

- Surface calculation – slab model
 - graphene sheet



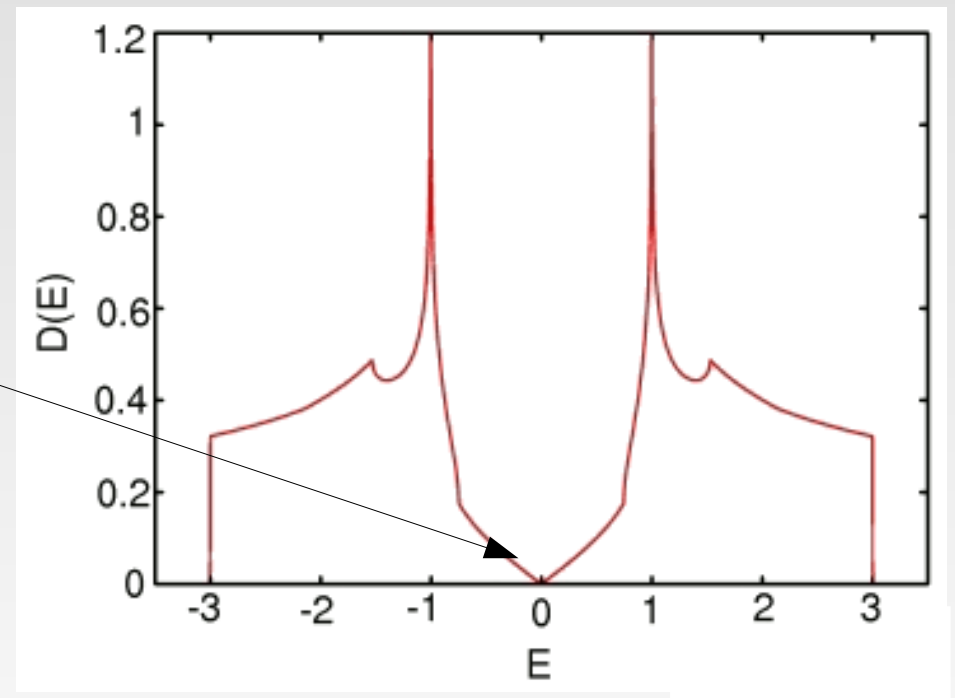
Graphene – free surface

- planar sheet of sp^2 carbons – honeycomb lattice
- building unit of graphite, nanotubes, fullerenes
- interesting properties



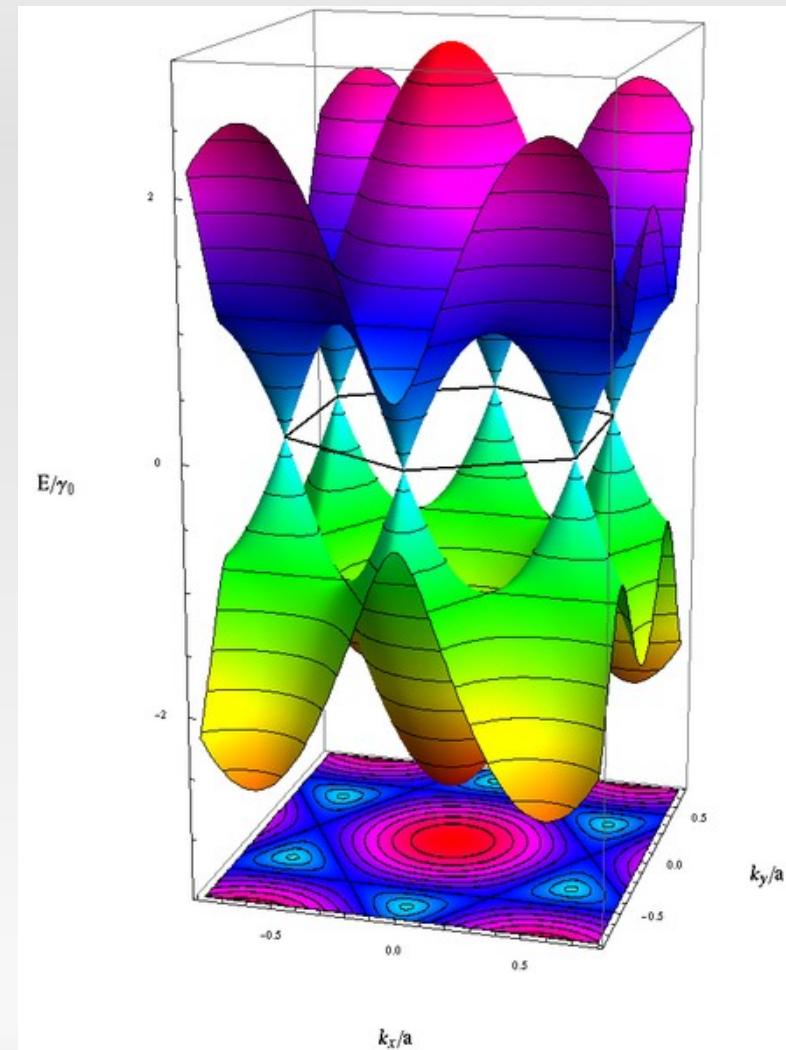
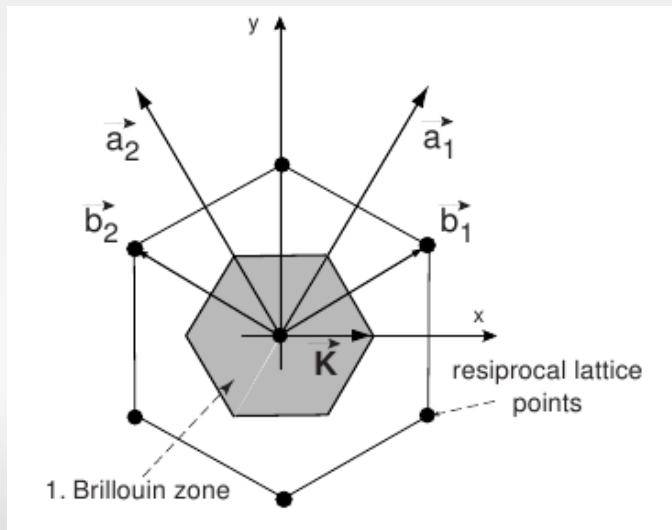
Graphene – free surface

- planar sheet of sp^2 carbons – honeycomb lattice
- building unit of graphite, nanotubes, fullerenes
- interesting properties
 - semi-metal or zero-gap semiconductor (ex. el_prop)
 - high electron mobility, low resistivity
 - strong material – breaking strength 200x higher than steel



Graphene – free surface

- interesting properties
 - semi-metal or zero-gap semiconductor (ex. el_prop)
 - high electron mobility, low resistivity
 - strong material – breaking strength 200x higher than steel

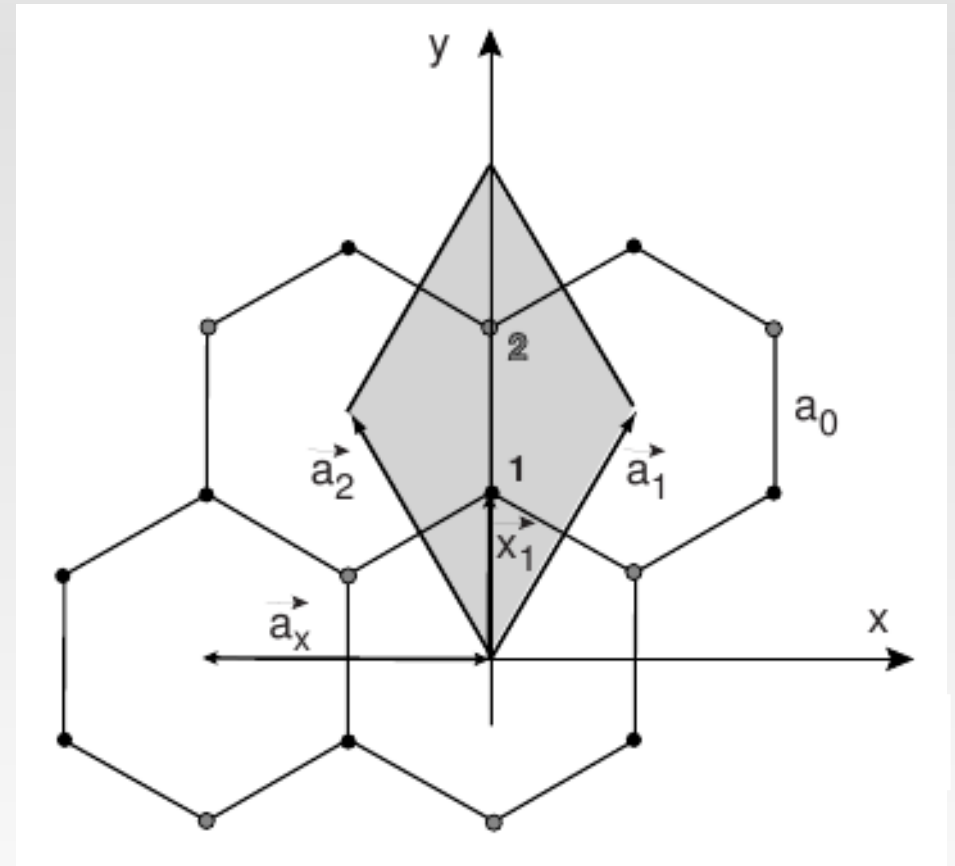


Graphene – free surface

- `cd cviceni_3/adsorption/gga/ex_1`
- POSCAR

```
Graphene
1.00
  1.229756  2.130000  0.000000
 -1.229756  2.130000  0.000000
  0.000000  0.000000 20.000000
C
2
Direct
0.333333 0.333333 0.000000
0.666667 0.666667 0.000000
```

- mind the large z component of last lattice vector - slab model – minimizing the interaction of plane images

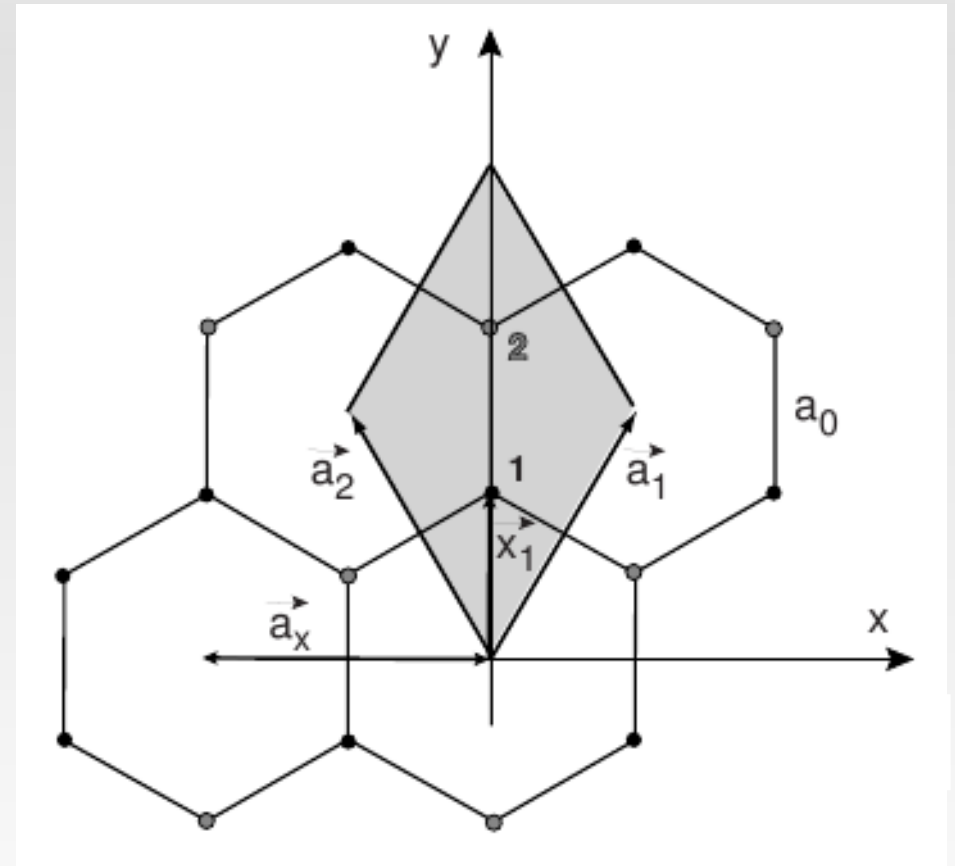


Graphene – free surface

- POSCAR

```
Graphene
1.00
  1.229756  2.130000  0.000000
 -1.229756  2.130000  0.000000
  0.000000  0.000000 20.000000
C
2
Direct
0.333333 0.333333 0.000000
0.666667 0.666667 0.000000
```

- mind the large z component of last lattice vector - slab model – minimizing the interaction of plane images



Graphene – free surface

- POSCAR

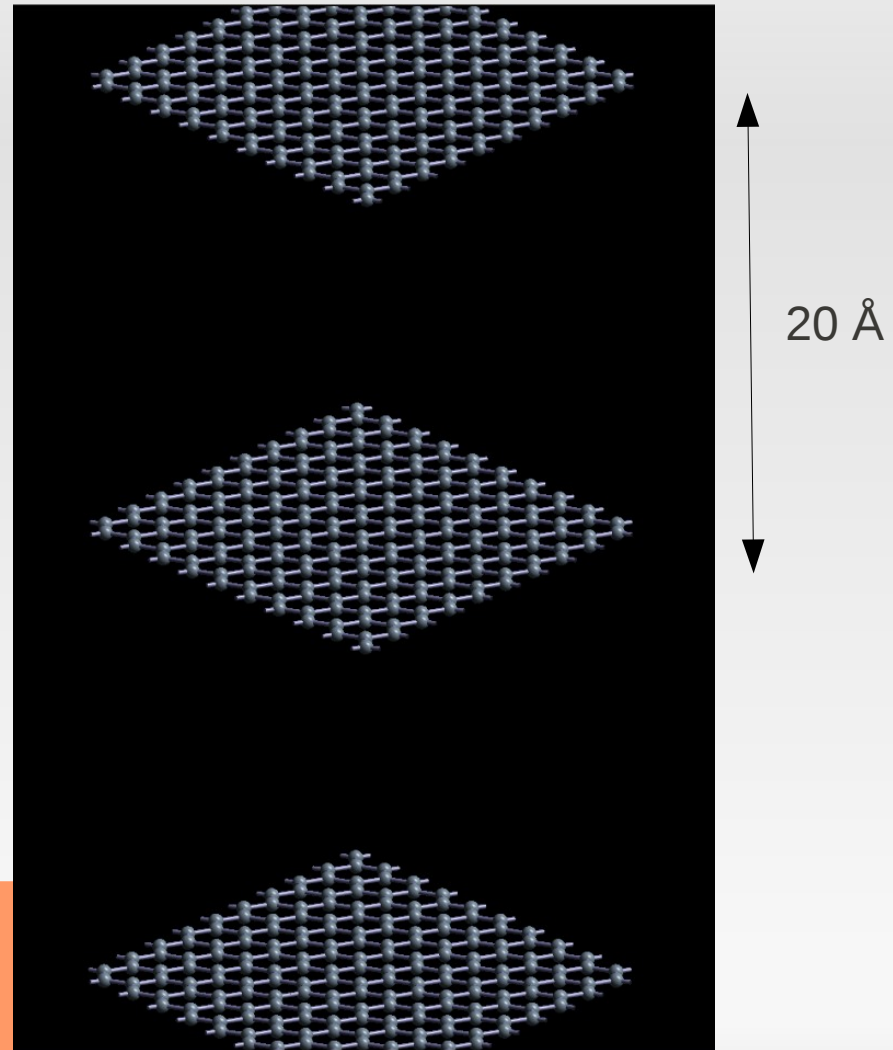
```
Graphene
1.00
  1.229756  2.130000  0.000000
 -1.229756  2.130000  0.000000
  0.000000  0.000000 20.000000
C
2
Direct
0.333333 0.333333 0.000000
0.666667 0.666667 0.000000
```

- mind the large z component of last lattice vector - slab model – minimizing the interaction of plane images

- KPOINTS

- in z-direction only few k-points – no interaction in this direction

```
Graphene
0
Monkhorst
7 7 2
0 0 0
```



Graphene – free surface

- POSCAR

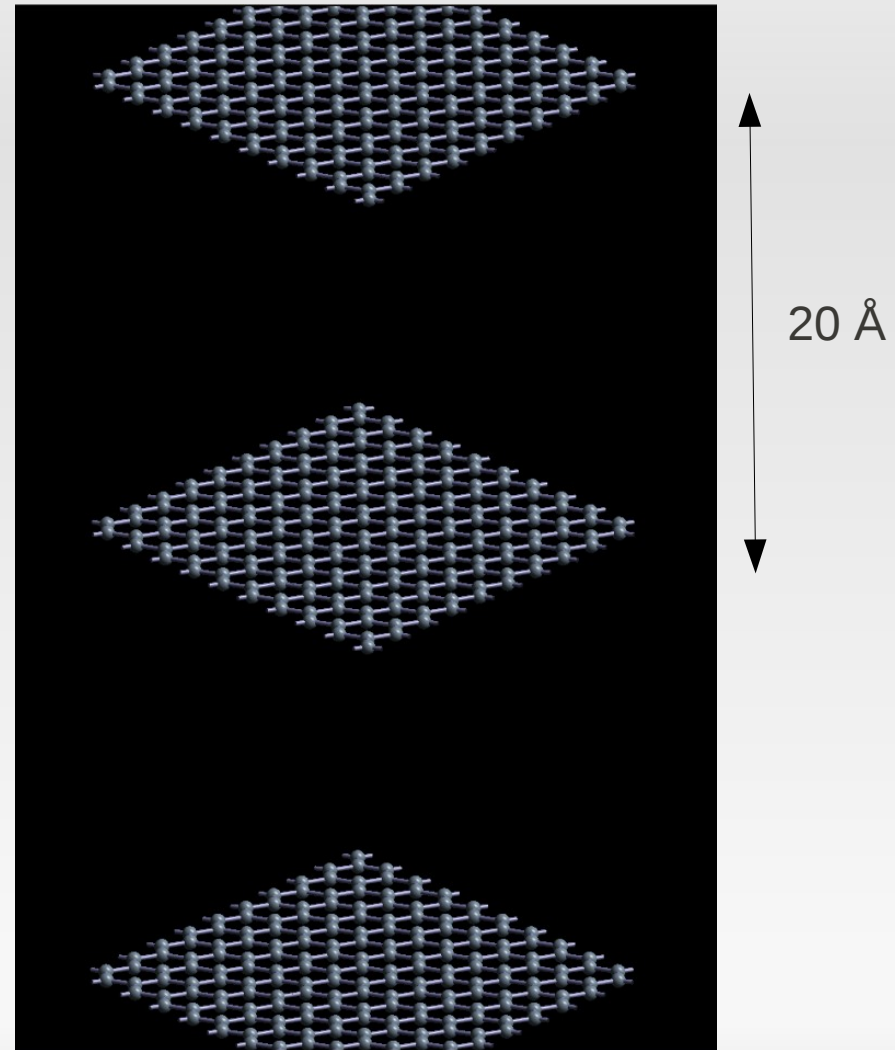
- mind the large z component of last lattice vector - slab model – minimizing the interaction of plane images

- KPOINTS

- in z-direction only few k-points – no interaction in this direction

- POTCAR

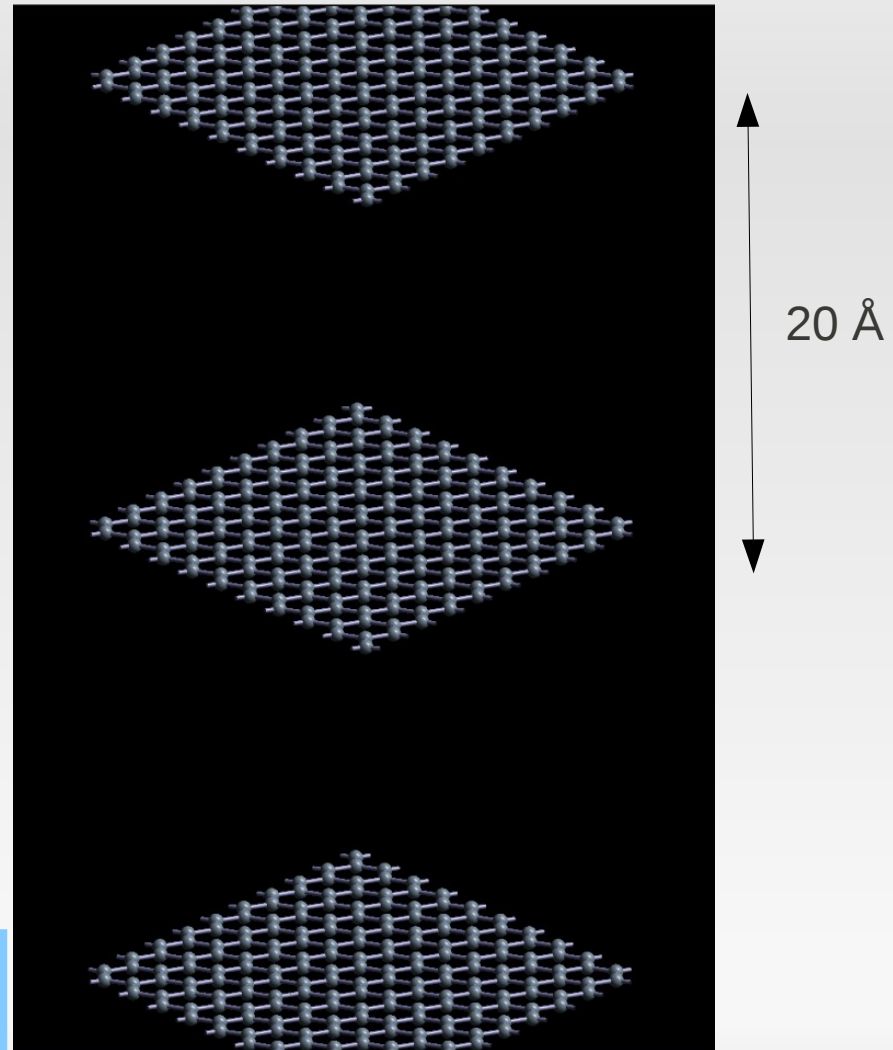
PROVIDED



Graphene – free surface

- POSCAR
 - mind the large z component of last lattice vector - slab model – minimizing the interaction of plane images
- KPOINTS
 - in z-direction only few k-points – no interaction in this direction
- INCAR and run VASP

```
SYSTEM = graphene  
NSW = 100  
IBRION = 2  
ISIF = 2  
ENCUT = 400  
ISMEAR = 0  
SIGMA = 0.05
```



Graphene – free surface

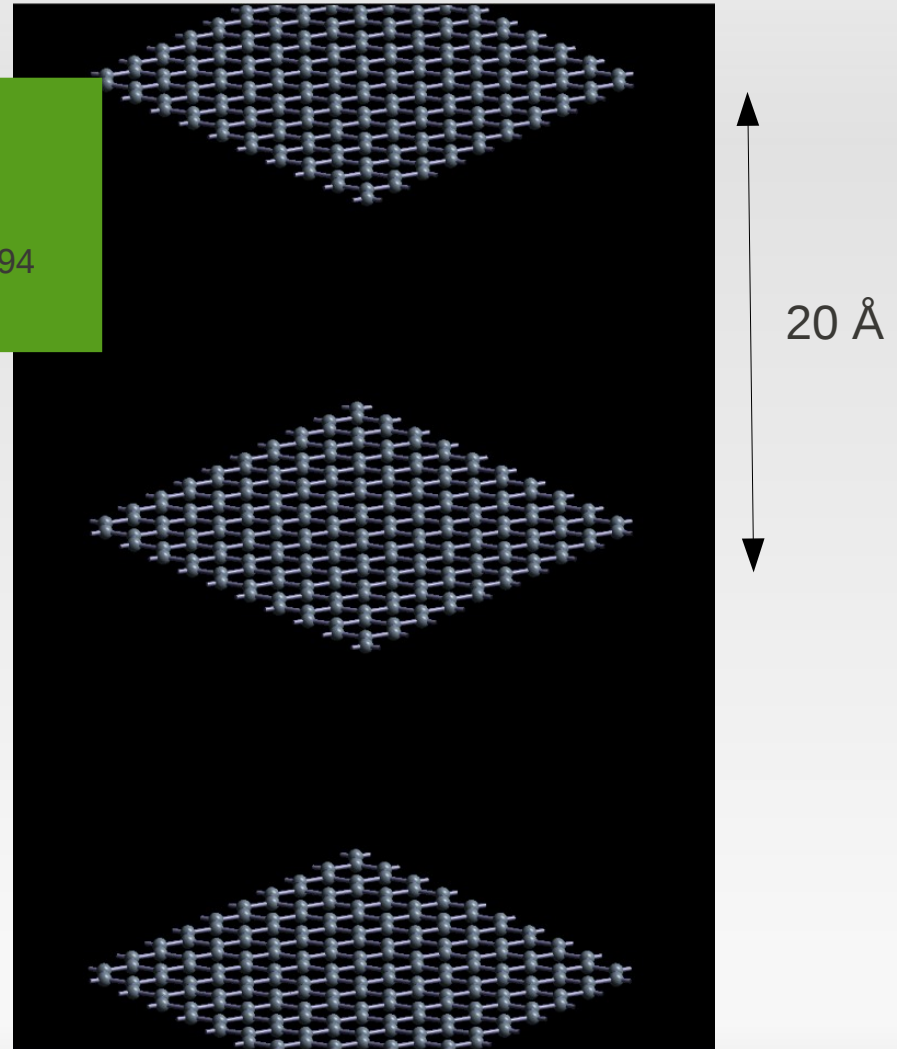
- OUTCAR

FREE ENERGIE OF THE ION-ELECTRON SYSTEM (eV)

free energy TOTEN = -18.471794 eV

energy without entropy= -18.471794 energy(sigma->0) = -18.471794

- $E(\text{graph}) = -18.471794 \text{ eV}$



Graphene – H₂ adsorption

- how to calculate adsorption on the surface?
 - $E_{\text{ads}} = E(\text{graph..H}_2) - E(\text{graph}) - E(\text{H}_2)$
- mind that the each energy contribution has to be calculated at the same level (ideally with the converged values of parameters) – cutoff value, k-points number, cell size, relaxed geometries
- `cd ../ex_2; copy KPOINTS and INCAR`
- POSCAR
- POTCAR
 - catenate the C and H POTCARs
- run VASP

Graphene and H2

1.00

1.229756	2.130000	0.000000
-1.229756	2.130000	0.000000
0.000000	0.000000	20.000000

C H

2 2

Direct

0.333333	0.333333	0.000000
0.666667	0.666667	0.000000
0.666667	0.666667	0.157500
0.666667	0.666667	0.194500

Graphene – H₂ adsorption

- how to calculate adsorption on the surface?
 - $E_{\text{ads}} = E(\text{graph}..H_2) - E(\text{graph}) - E(H_2)$
- mind that the each energy contribution has to be calculated at the same level (ideally with the converged values of parameters) – cutoff value, k-points number, cell size, relaxed geometries
- `cd ../ex_2; copy KPOINTS and INCAR`
- POSCAR
- POTCAR
 - catenate the C and H POTCARs
- run VASP and look at the OUTCAR
 - $E(\text{graph}...H_2) = -25.090832 \text{ eV}$

Graphene and H2

1.00

1.229756	2.130000	0.000000
-1.229756	2.130000	0.000000
0.000000	0.000000	20.000000

C H

2 2

Direct

0.333333	0.333333	0.000000
0.666667	0.666667	0.000000
0.666667	0.666667	0.157500
0.666667	0.666667	0.194500

Graphene – H₂

- how to calculate adsorption on the surface?
 - $E_{\text{ads}} = E(\text{graph}..H_2) - E(\text{graph}) - E(H_2)$
- mind that the each energy contribution has to be calculated at the same level (ideally with the converged values of parameters) – cutoff value, k-points number, cell size, relaxed geometries
- `cd ../ex_3; copy KPOINTS and INCAR`
- POSCAR
- POTCAR
 - only H POTCAR
- run VASP and look at the OUTCAR
 - $E(H_2) = -6.617838 \text{ eV}$

```
Graphene and H2
1.00
1.229756 2.130000 0.000000
-1.229756 2.130000 0.000000
0.000000 0.000000 20.000000
H
2
Direct
0.666667 0.666667 0.157500
0.666667 0.666667 0.194500
```

$E_{\text{ads}} = -0.0012 \text{ eV} \Rightarrow -0.1 \text{ kJ/mol}$ - very weak interaction

Graphene – GGA vs. LDA

- the experimental value of the H₂ adsorption ~ -5 kJ/mol
- large discrepancy for DFT/GGA used (~ -0.1kJ/mol) due to incapability to correctly describe weakly (VdW) bound complexes
- but it was observed that DFT/LDA gives in this case much more satisfying results although due to some error compensation
- copy needed files (or all) to `cviceni_3/adsorption/lda/`
- only use different POTCARs
 - `~grajciar/School/QCH_VASP_exercises/potpaw_LDA/`
- run VASP and check the OUTCARs/OSZICARs
-

Graphene – DOS

- analogous to previous DOS calculation with fcc Si
- `cd exercises_3/dos/ex_1`; copy POSCAR and POTCAR from previous graphene runs
- INCAR
- KPOINTS – finer grid used
- run VASP
- copy input files along with CHGCAR to `../ex_2/`
- change INCAR and use even finer k-point grid
- rerun VASP
- visualize

```
SYSTEM = graphene
ENCUT = 400
ISMEAR = -4
SIGMA = 0.05
```

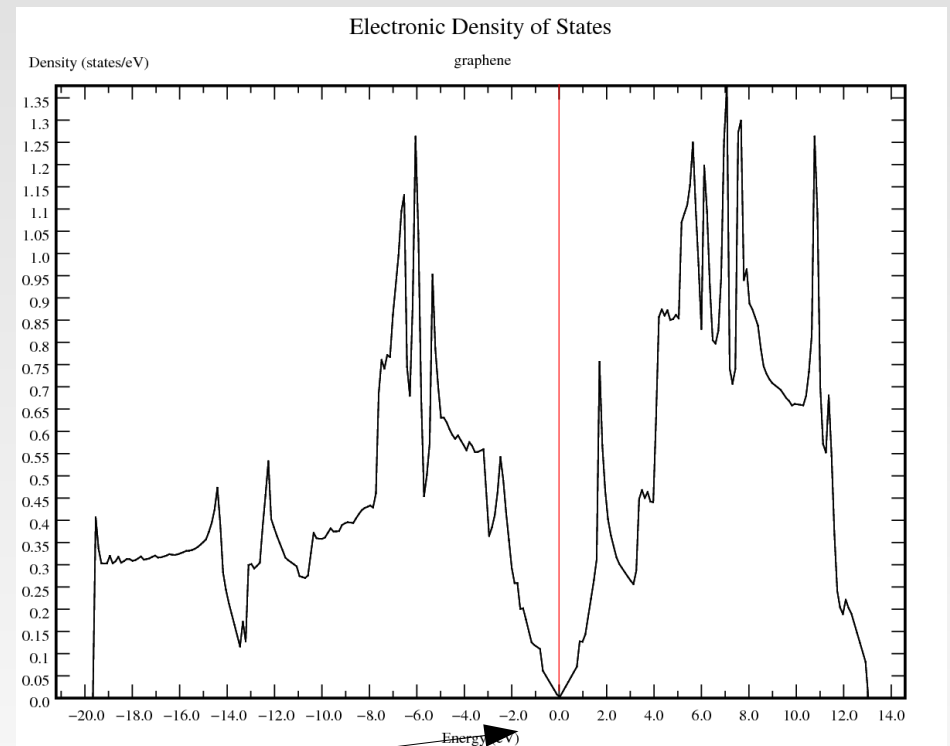
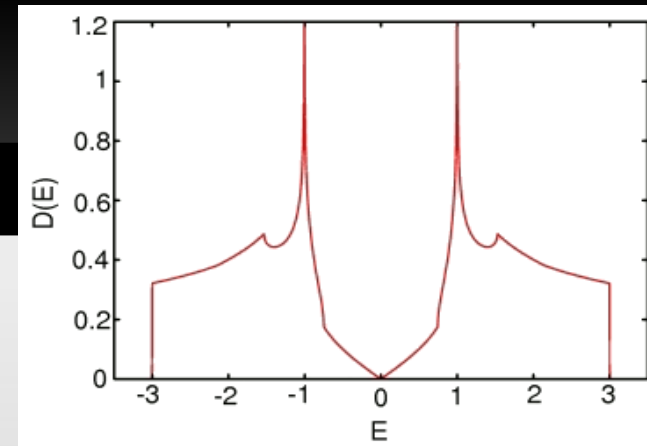
```
Graphene
0
Monkhorst
11 11 1
0 0 0
```

```
SYSTEM = graphene
ICHARG = 11
ENCUT = 400
ISMEAR = -4
SIGMA = 0.05
```

```
Graphene
0
Monkhorst
21 21 1
0 0 0
```


Graphene – DOS

- analogous to previous DOS calculation with fcc Si
- `cd exercises_3/dos/ex_1;`
copy POSCAR and POTCAR from previous graphene runs
- INCAR
- KPOINTS – finer grid used
- run VASP
- copy input files along with CHGCAR to `../ex_2/`
- change INCAR and use even finer k-point grid
- rerun VASP
- visualize



Graphene – band-structure

- analogous to previous band-structure calculation with fcc Si
- `cd exercises_3/band/ex_1; copy POSCAR, POTCAR and CHGCAR from previous run (dos/ex_1)`
- INCAR
- KPOINTS
 - k-points along x and y axis of k-space

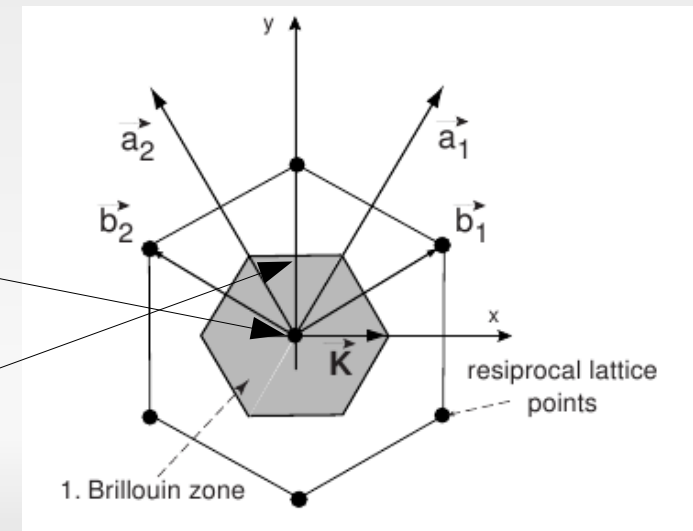
```
SYSTEM = graphene
ICHARG=11
ENCUT = 400
ISMEAR = 0
SIGMA = 0.05
```

```
Graphene
20
line
cartesian
-0.384900179 0 0 1 !-kx
0.000000000 0 0 1 !Gamma

0.000000000 0 0 1 !Gamma
0.384900179 0 0 1 !+kx

0 -0.384900179 0 1 !-ky
0 0.000000000 0 1 !Gamma

0 0.000000000 0 1 !Gamma
0 0.384900179 0 1 !+ky
```



Graphene – band-structure

- analogous to previous band-structure calculation
- `cd exercises_3/band/ex_1; copy POSCAR CHGCAR from previous run (dos/ex_1)`
- INCAR
- KPOINTS
 - k-points along x and y axis of k-space

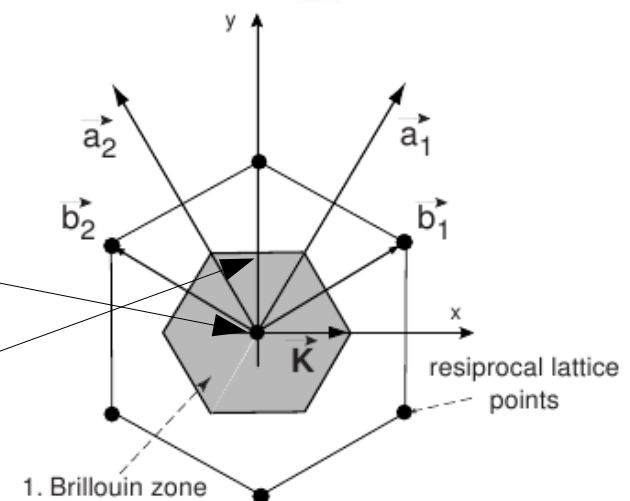
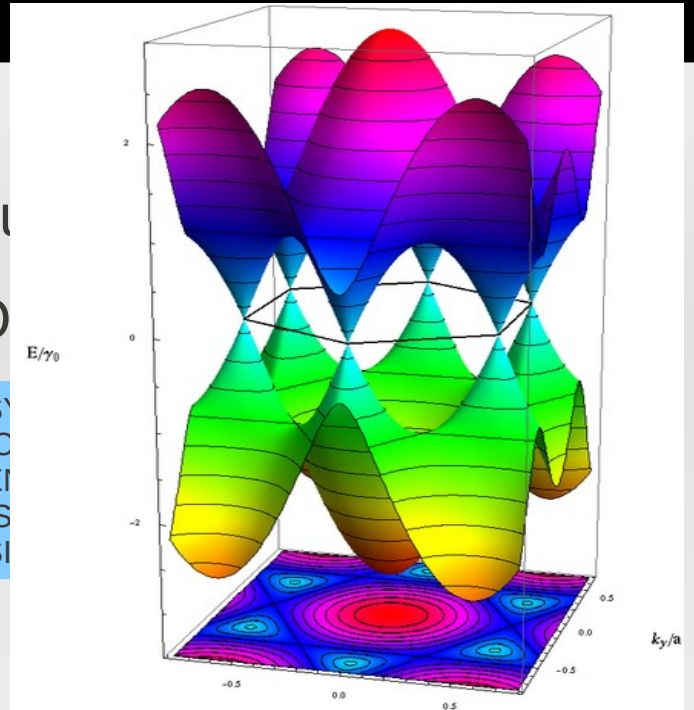
```

Graphene
20
line
cartesian
-0.384900179 0 0 1 !-kx
0.000000000 0 0 1 !Gamma

0.000000000 0 0 1 !Gamma
0.384900179 0 0 1 !+kx

0 -0.384900179 0 1 !-ky
0 0.000000000 0 1 !Gamma

0 0.000000000 0 1 !Gamma
0 0.384900179 0 1 !+ky
    
```

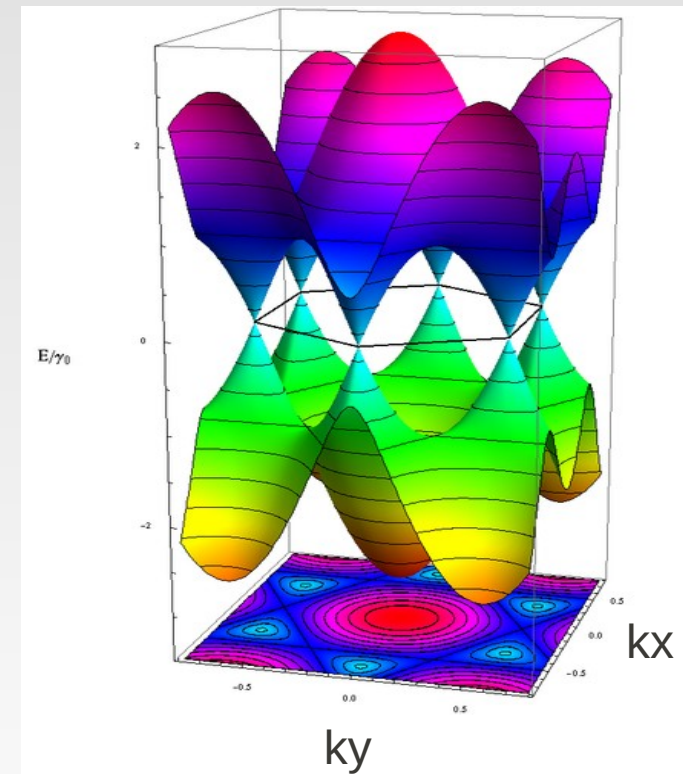
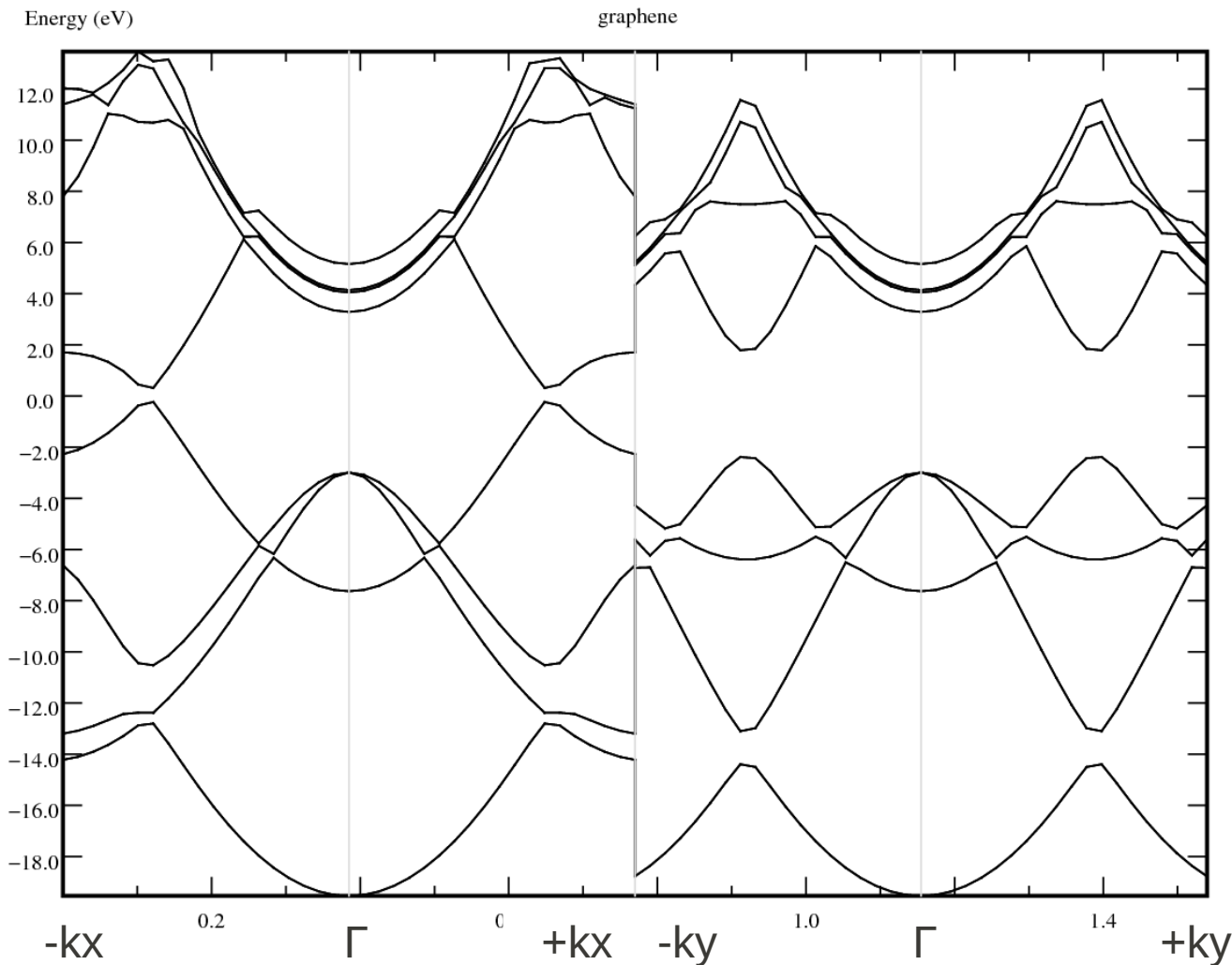


Graphene – band-structure

- run VASP and visualize

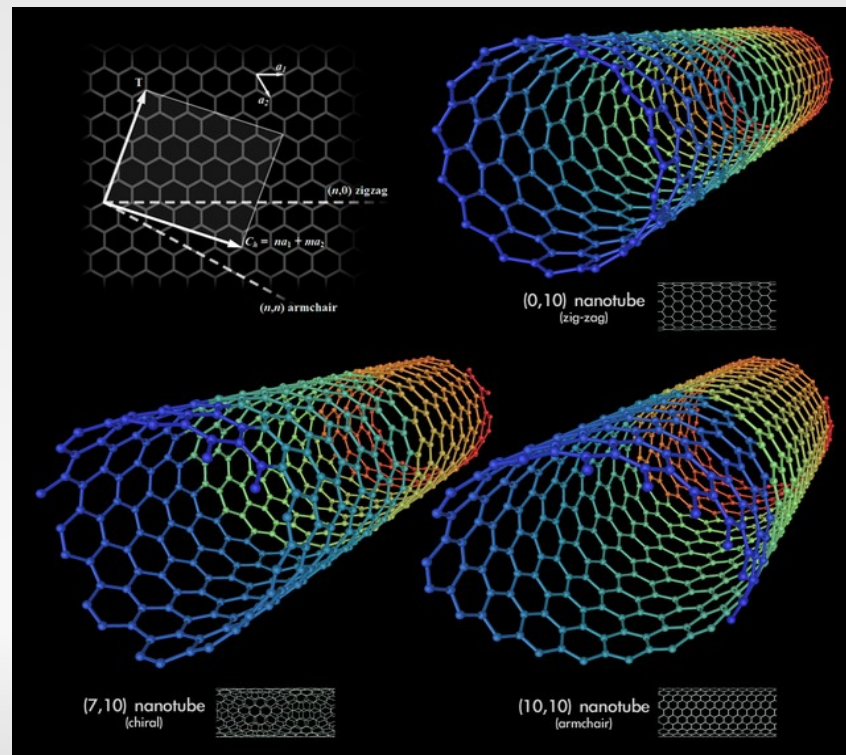
Bandstructure

graphene



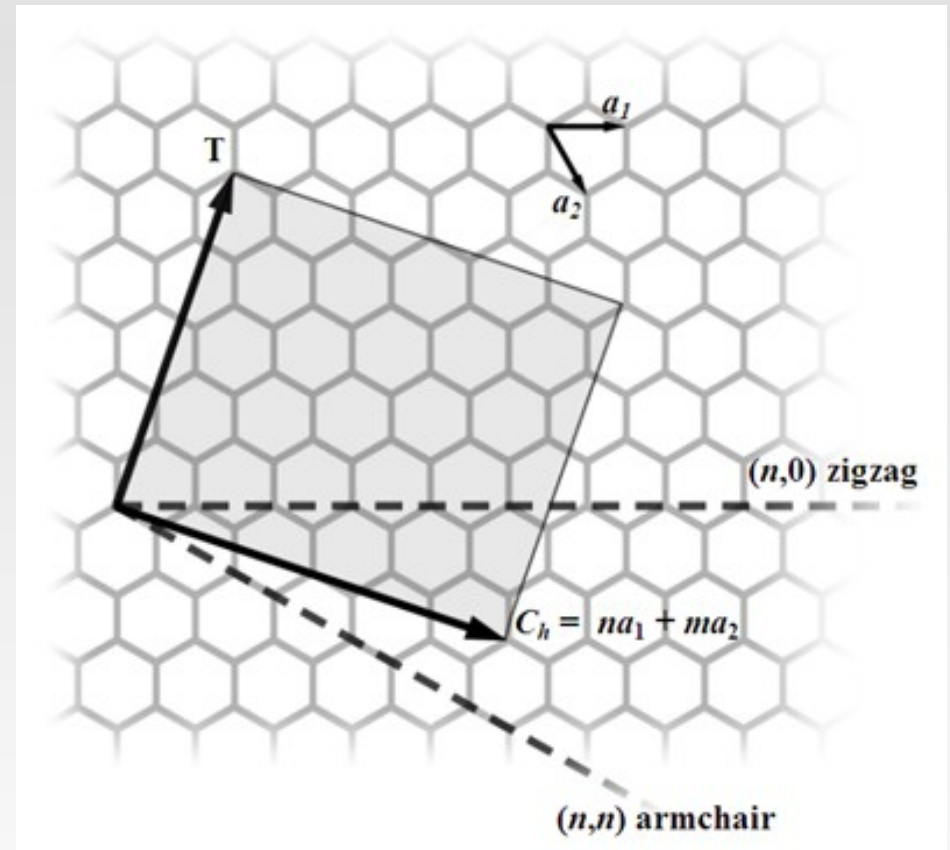
Outline

- Surface calculation – slab model
 - graphene sheet
- Optional – carbon nanotubes



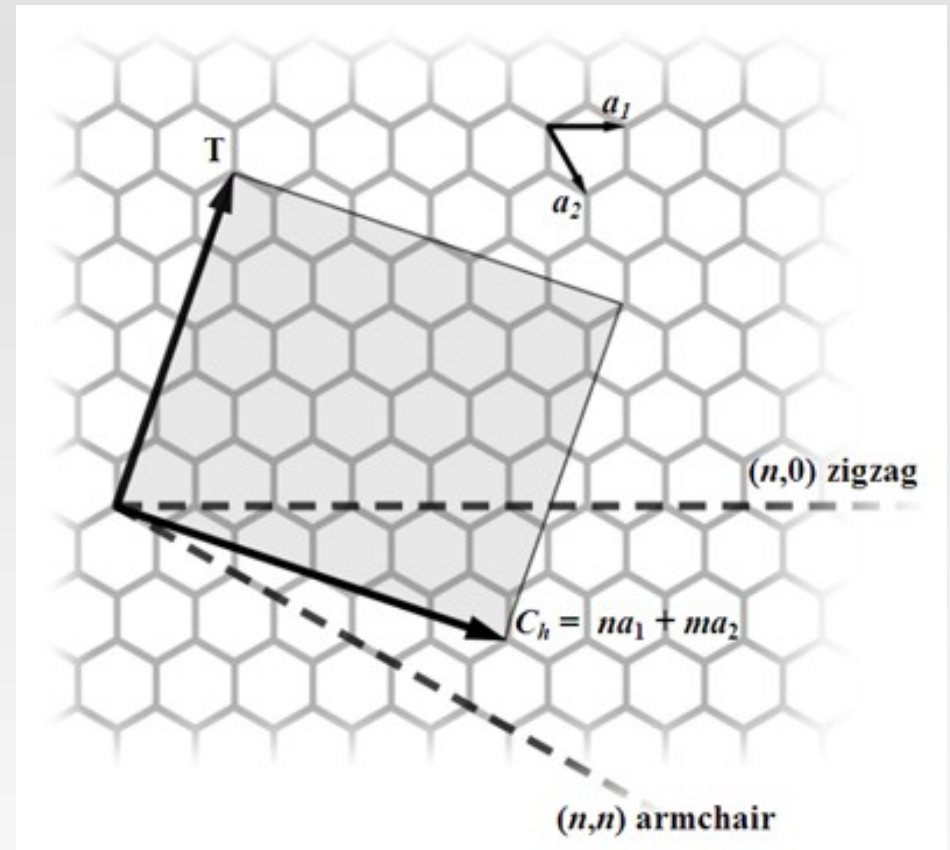
Carbon nanotubes

- wrapping the graphene sheet to seamless cylinder
- different ways to wrap a graphene leading to nanotubes with different properties – metallic/semiconductor



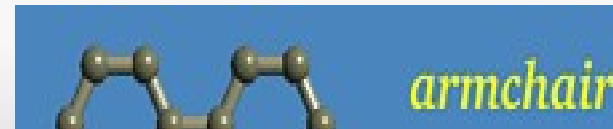
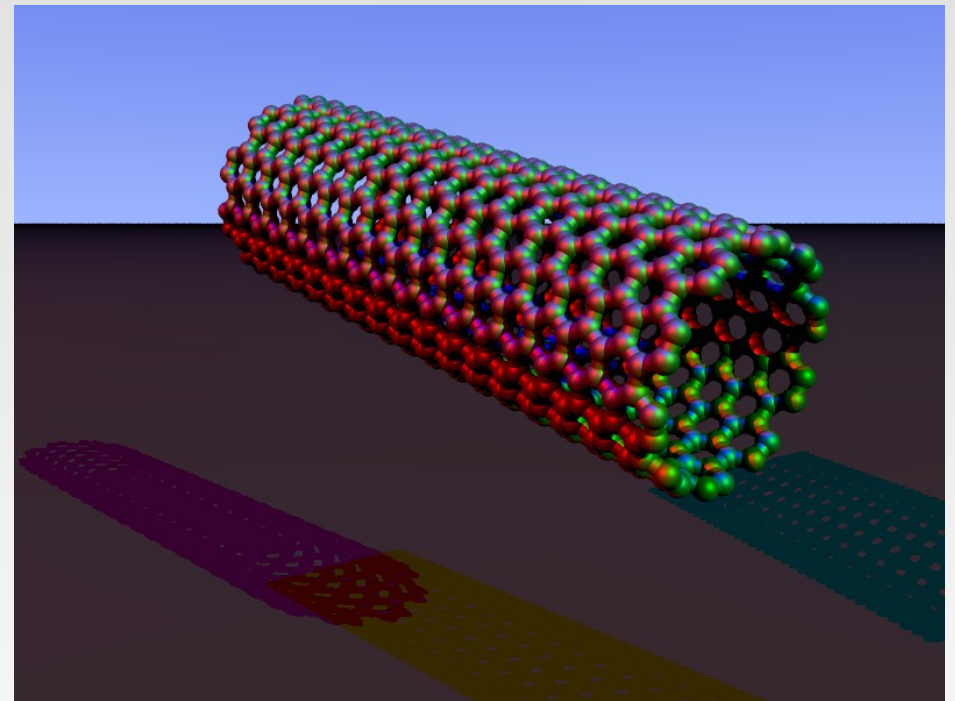
Carbon nanotubes

- wrapping the graphene sheet to seamless cylinder
- different ways to wrap a graphene leading to nanotubes with different properties – metallic/semiconductor
- the (n,m) naming adopted – the integer prefactors for the unit vectors a_1 and a_2
- T – the tube axis
- C_h – the “roll up” vector



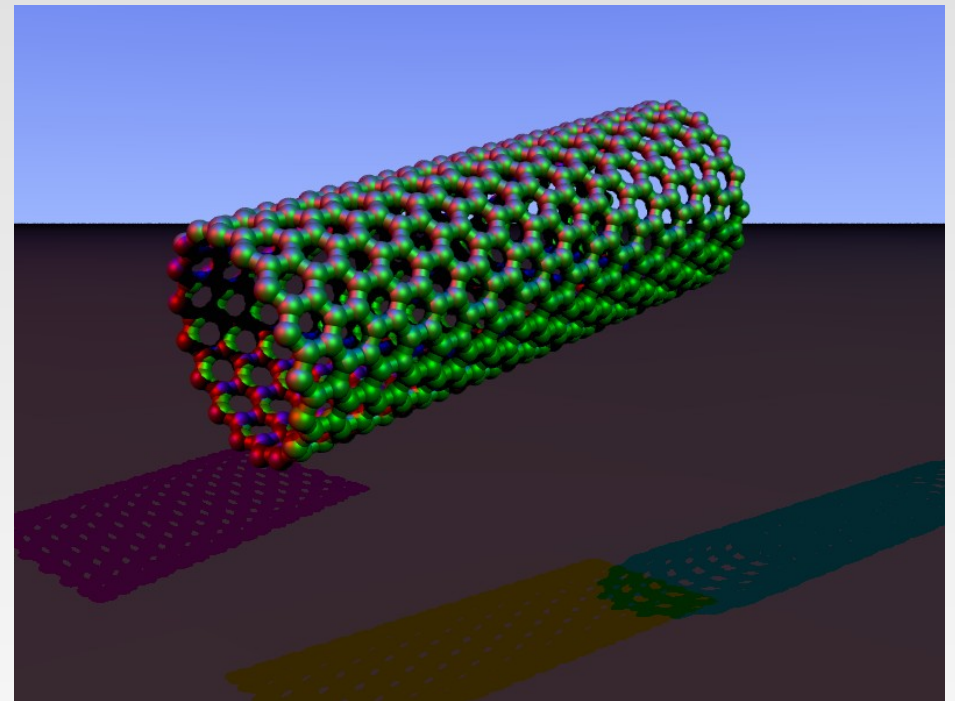
Carbon nanotubes

- wrapping the graphene sheet to seamless cylinder
- different ways to wrap a graphene leading to nanotubes with different properties – metallic/semiconductor
- the (n,m) naming adopted – the integer prefactors for the unit vectors a_1 and a_2
- T – the tube axis
- C_h – the “roll up” vector
- $n=m$ – the armchair – metallic behaviour



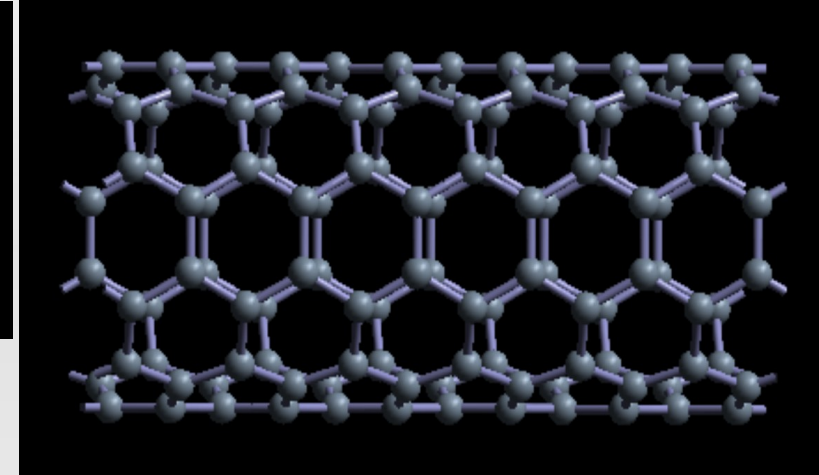
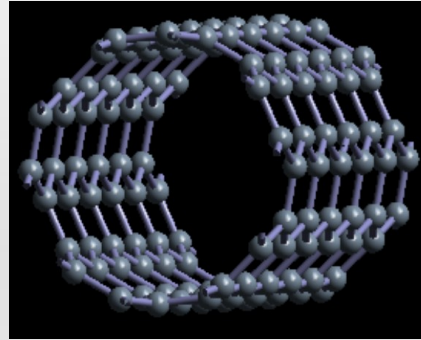
Carbon nanotubes

- the (n,m) naming adopted – the integer prefactors for the unit vectors a_1 and a_2
- T – the tube axis
- C_h – the “roll up” vector
- $m=0$ – the zigzag (otherwise – the chiral)
- if $n-m = 3*Z$, Z is integer \Rightarrow tiny-gap semiconductor
- otherwise large-gap semiconductor
- the gaps decreases with the tube diameter



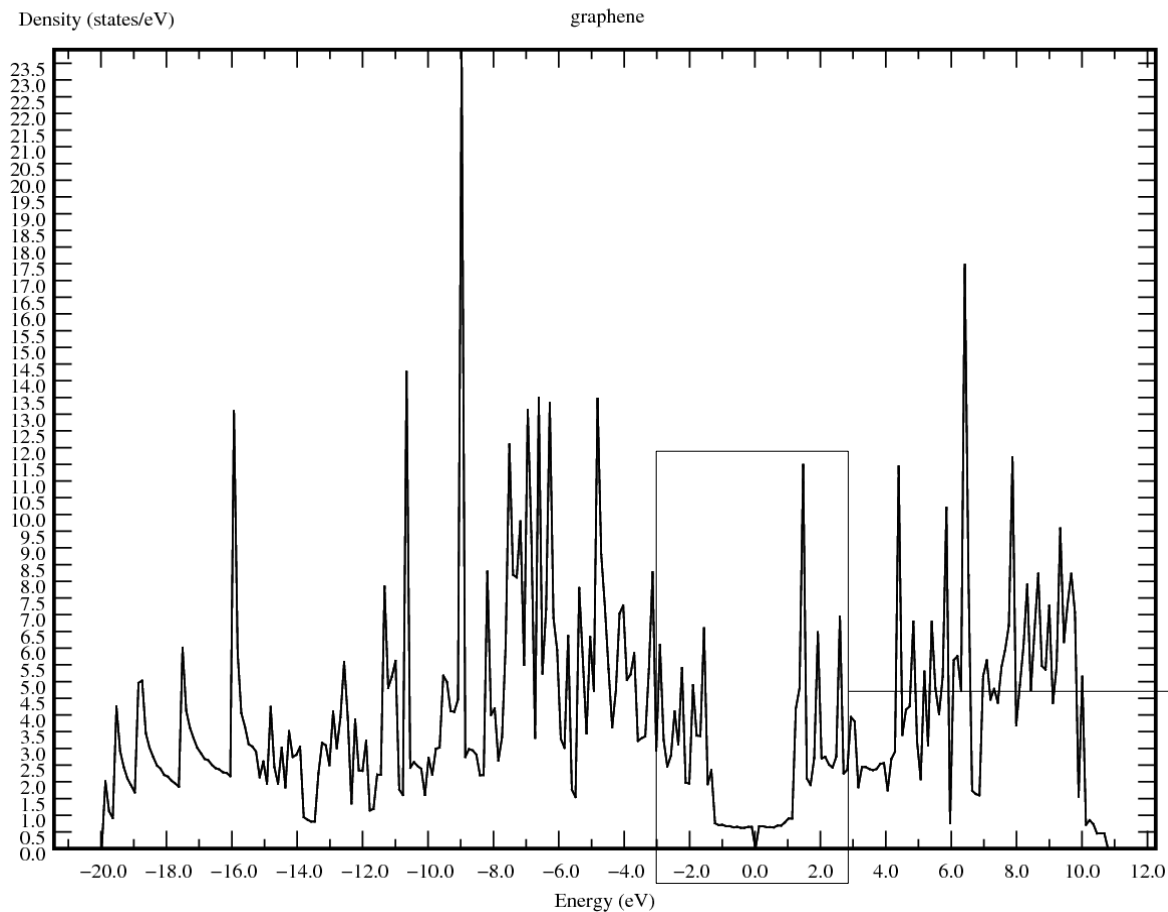
Examples – (5,5) SWNT

- VASP calculation
- DOS - metallic



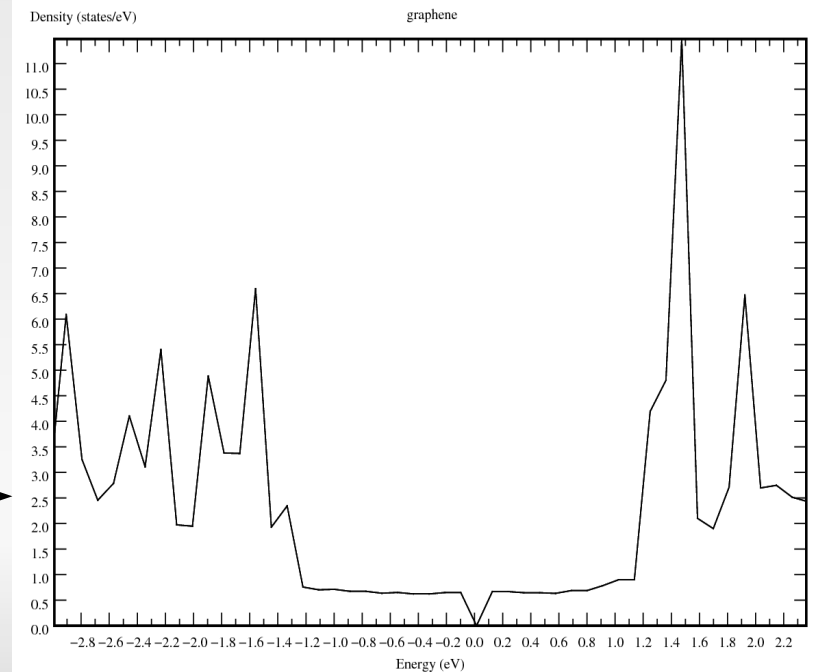
Electronic Density of States

graphene



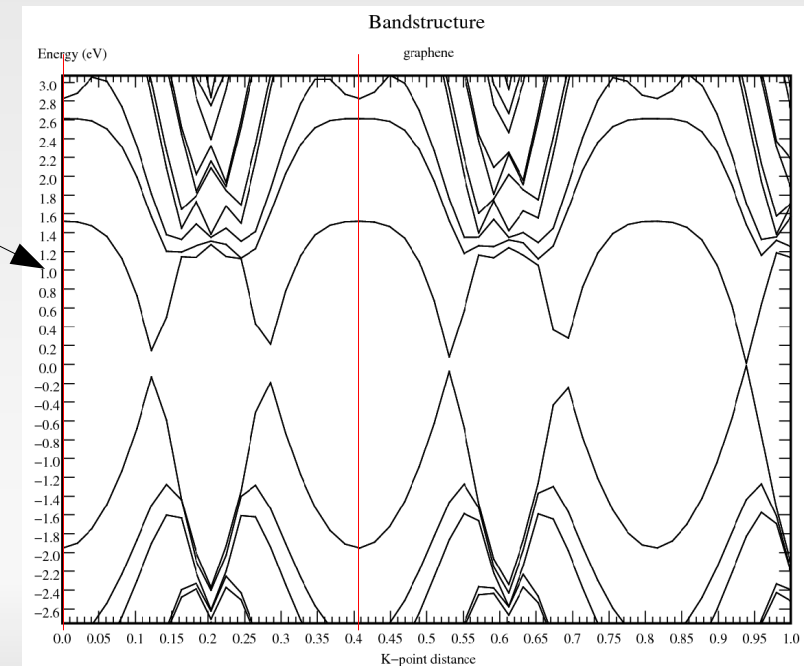
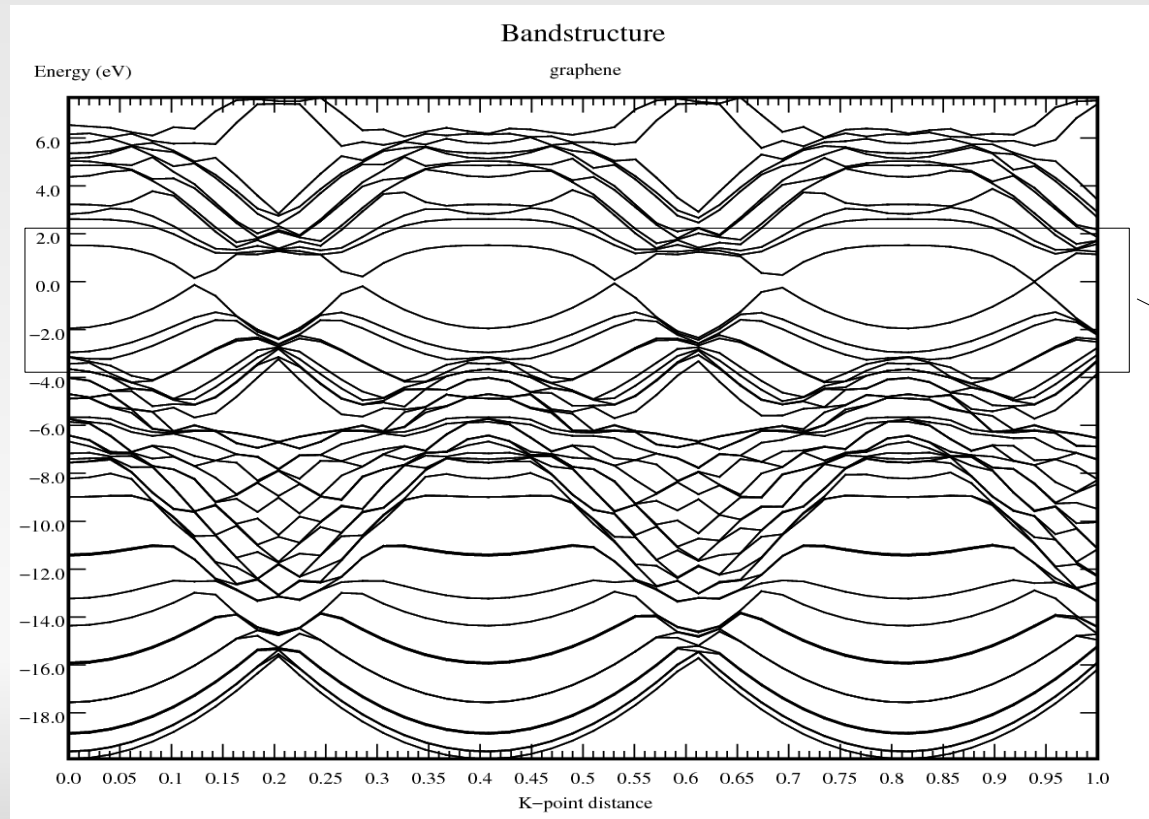
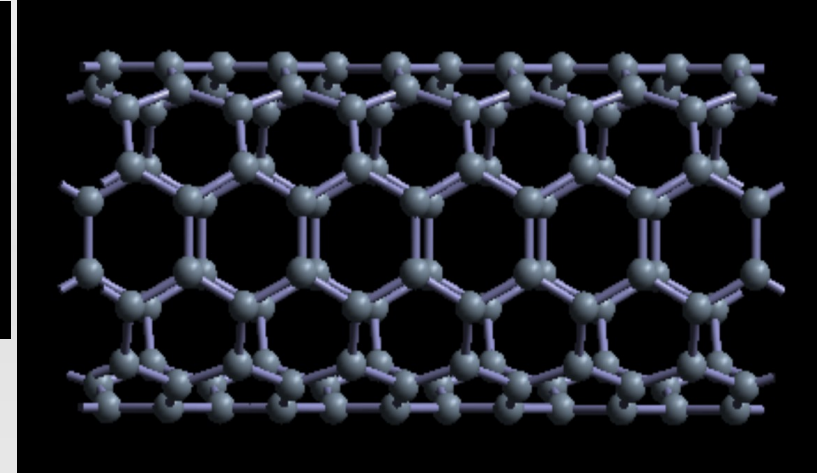
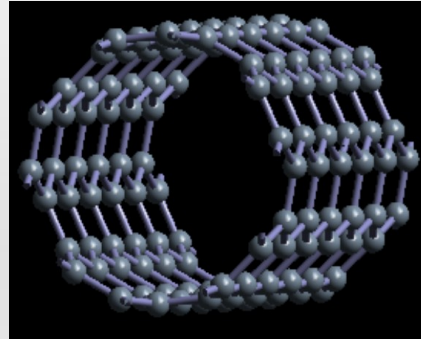
Electronic Density of States

graphene



Examples – (5,5) SWNT

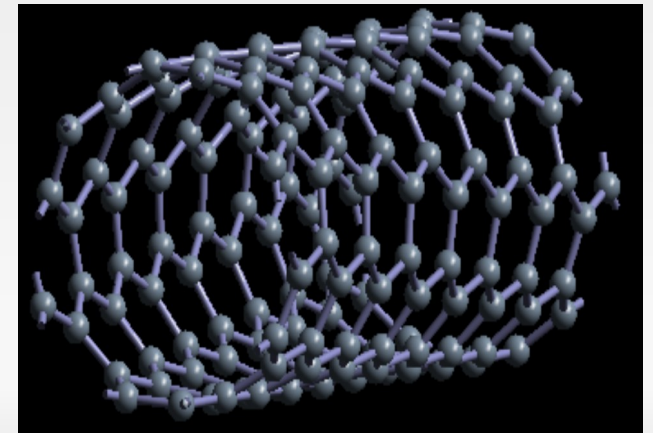
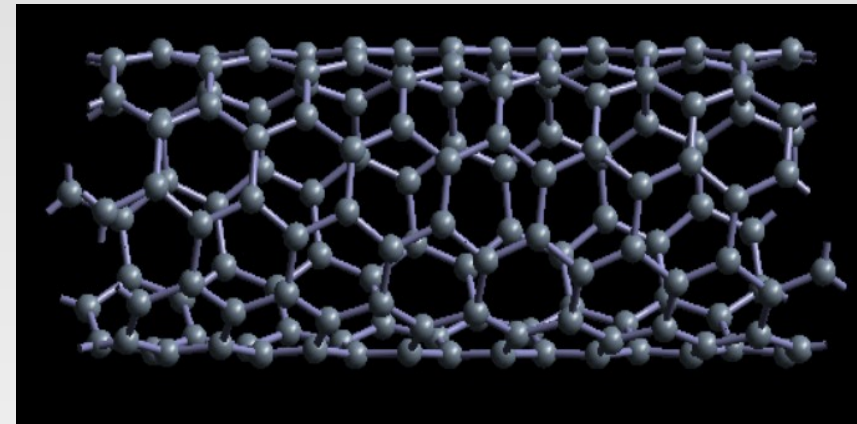
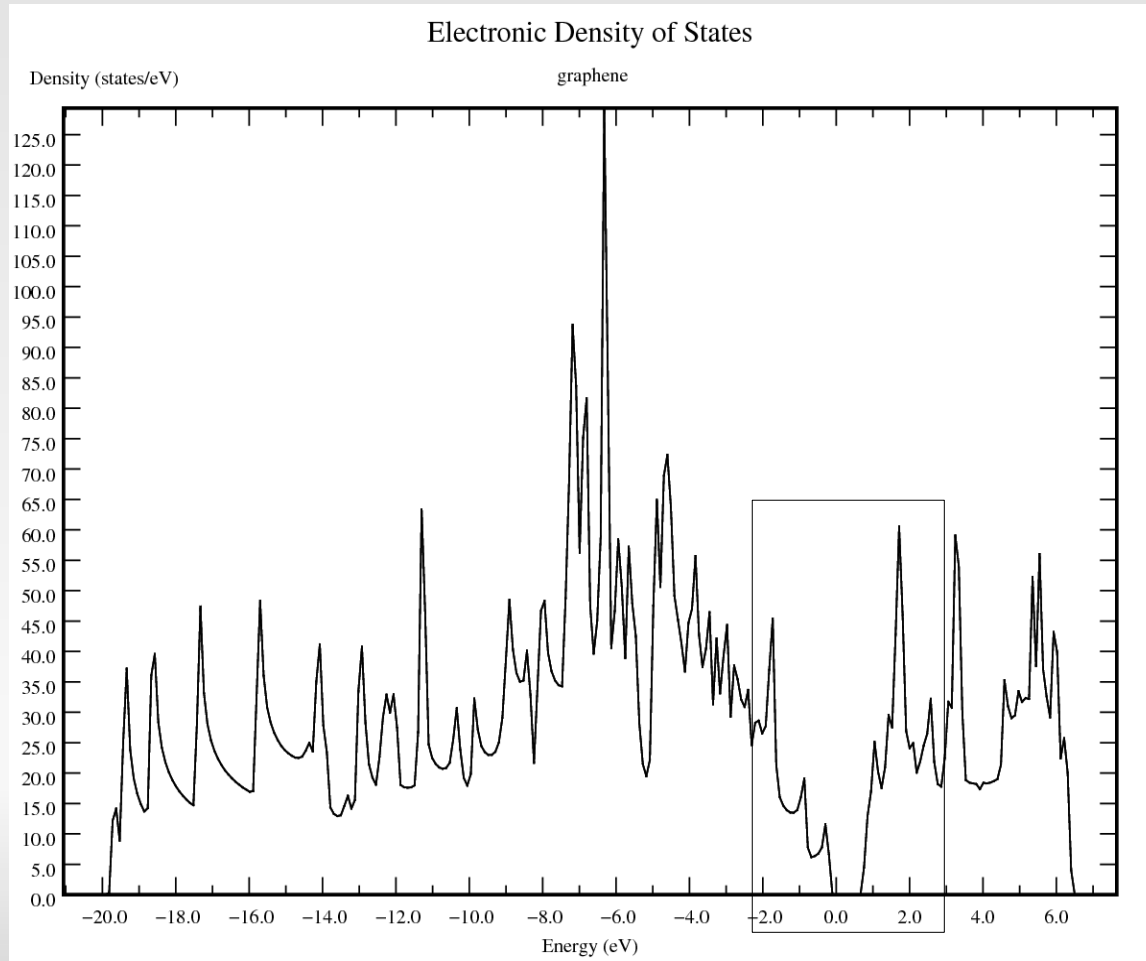
- VASP calculation
- Band-structure
 - scan along the z-direction - k_z



1. BZ

Examples – (6,4) SWNT

- VASP calculation
- DOS - semi-conductor



Examples – (6,4) SWNT

- VASP calculation
- Band-structure – band-gap present

